

Plagiarism Detection Report

Report ID: f1cf308a-34cc-40b1-b4c6-3ce5ddd85875

Date: 2026-02-11 13:59:01

Overall Plagiarism Score: 0.0%

Verdict: Clean

Explanation: Analysis Complete. Readability: Fairly Difficult (59.81761638749825). Spelling Errors: 379.

Sentence Analysis:

[LOW] Similarity: 4.38%

Sentence: 9 IV April 2021

International Journal for Research in Applied Science & Engineering Technology (IJRASET)

ISSN: 2321 -9653; IC Value: 45.98; SJ Impact

Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

994 Spin Coated Al Doped ZnO Thin Film for Optical

Application; Morphology and Optical Studies

Dr. S. Ashok Raj¹, Dr. P. Prabu², B. Dhivakar³

¹Assistant Professor , PG and Research department of physics, Government Arts College (Autonomous)

Kumbakonam, Tamil Nadu

²Principal , Ponnaiyah Ramajayam Polytechnic College , Prist Deemed to be University, Thanjavur, Tamil Nadu

³M.Phil Scholar , Department of Physics, Prist Deemed to be University, Thanjavur, Tamil Nadu

Abstract: The different molar concentration (1-4Mole) of Aluminium Chloride Anhydrite was doped with

Plagiarism Detection Report

Zinc acetate dehydrate

(ZnO) thin film on glass substrate by spin coating process.

[LOW] Similarity: 5.20%

Sentence: T he morphological and an optical property of AZO thin films were investigated .

[LOW] Similarity: 5.56%

Sentence: The X -Ray diffractometer results show that nature and the successful changes of Al at Zn O site in ZnO thin film.

[LOW] Similarity: 3.85%

Sentence: Further with Al doping, the crystalline size, and film thickness were found.

[LOW] Similarity: 8.33%

Sentence: Also, SEM results shows that spherical grains sizes of the films.

[LOW] Similarity: 3.12%

Sentence: Room temperature photoluminescence measurements were carried out using a spectrofluorometer using an excitation wavelength of 250 nm.

[LOW] Similarity: 6.67%

Sentence: PL spectra shows the Al doped ZnO thin films the electrons of Al³⁺ ion will be released when Zn²⁺ is replaced by Al³⁺, so the increase of carrier concentration can improve the conductivity of the thin film.

[LOW] Similarity: 5.38%

Sentence: The functional group was confirmed with FTIR spectrum.

Plagiarism Detection Report

[LOW] Similarity: 3.57%

Sentence: The optical transmittance measurement was carried out using UV -VIS spectrophotometer.

[LOW] Similarity: 6.06%

Sentence: The obtained results of all thin films are discussed in detail and are compared with other experimental results.

[LOW] Similarity: 1.79%

Sentence: Keywords: ZnO -Zinc acetate dehydrate, Al -Aluminium Chloride Anhydrite, FTIR - Fourier Transform Infrared Spectroscopy, UV-VI-Ultraviolet -Visible -near -IR Spectroscopy, PL-photoluminescence.

[LOW] Similarity: 0.00%

Sentence: I.

[LOW] Similarity: 3.45%

Sentence: INTRODUCTION

Over the past few decades, Zinc acetate dehydrate (ZnO) is one of the generally considered material among II -VI semiconductors because of its wide band gap (3.2eV) and huge exciton restricting energy of (60 meV), which is twice bigger than that of Gallium Nitride (GaN) (28meV)[1].

[LOW] Similarity: 2.78%

Sentence: Because of peculiar properties, ZnO finds many technological applications in the field of optoelectronic [1], gas sensors [2] and solar cells [3], etc.

[LOW] Similarity: 5.71%

Sentence: In the current innovation, indium tin oxide (ITO) and GaN are discovered to be

Plagiarism Detection Report

the promising materials for TCO and optoelectronic gadget applications, respectively.

[LOW] Similarity: 3.70%

Sentence: However, in the last few years, group III components, specifically Al, doped ZnO thin film considered the alternative material of ITO, due to low cost, it also inform that, AZO thin film exhibit the good chemical, mechanical and thermal stability.

[LOW] Similarity: 7.14%

Sentence: ZnO is the alternative material for optoelectronic applications when doped with Al[3].

[LOW] Similarity: 8.57%

Sentence: It is realized that, in pure ZnO thin film the observed photoluminescence is attributed to the presence of native defects in the material [4].

[LOW] Similarity: 12.12%

Sentence: It is interesting to research the impact of Al doping and its concentration on the structure of the thin films, which affects the optical and photoluminescence properties.

[LOW] Similarity: 4.65%

Sentence: Till now, thin film is prepared using various methods such as spray pyrolysis, sputtering, sol-gel spin coating, pulsed laser deposition (PLD), chemical vapour deposition (CVD) [10-16].

[LOW] Similarity: 9.30%

Sentence: In spite of few studies regarding to the sol-gel method, the sol-gel method has some advantage, such as the easy control of chemical components, and manufacture of thin film at a low cost and its simplicity.

Plagiarism Detection Report

[LOW] Similarity: 6.45%

Sentence: In recent time reported that the films with increased optical properties with high sol concentration of 1 mol/ml [5].

[LOW] Similarity: 9.68%

Sentence: Further, it is also reported that, improvement in the defect related photoluminescence with the increase of sol concentration [6].

[LOW] Similarity: 6.25%

Sentence: The obtained results of all thin films are discussed in detail and are compared with other experimental results.

[LOW] Similarity: 0.00%

Sentence: II.

[LOW] Similarity: 3.05%

Sentence: EXPERIMENTAL METHODS

The sol -gel spin coating method was used to prepare the ZnO thin film deposited on the glass substrates.

[LOW] Similarity: 0.70%

Sentence: Zine Acetate Dehydrate

(ZnCH₃COO₂) is a Starting material, 2 -Methoxy Ethanol (2-MEA) is Solvent, Aluminium Chloride Anhydrite are Dopant , and

Diethanolamine (DEA) was used as a stabilizer.

[LOW] Similarity: 3.42%

Sentence: The Zine acetate dehydrate were dissolved in 2 -Methoxy ethanol (2-MEA) at room temperature to obtain origin solution (A), the mixture was stirred at 60-C and the stabilizer Diethanolamine (DEA) was add ed in drop wise until the clear solution was obtained.

Plagiarism Detection Report

[LOW] Similarity: 4.17%

Sentence: The Aluminium chloride Anhydrite were dissolved in 2 -Methoxy ethanol (2-MEA) at room temperature to obtain the dopant solution (B), the mixture was stirred at 60-C and achieved the clear solution .

[LOW] Similarity: 8.11%

Sentence: Then solution (A) is added drop wise to the solution (B) in order to obtain the stoichiometry solution of pure (1 -4 mol %) Al doped ZnO.

[LOW] Similarity: 4.43%

Sentence: The solution were stirred at 60-C for 2 hrs to obtain homogeneous mixture and then aged at room temperature for 48 hrs.

[LOW] Similarity: 2.82%

Sentence: International Journal for Research in Applied Science & Engineering Technology (IJRASET)
ISSN: 2321 -9653; IC Value: 45.98; SJ Impact
Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

995 The concentration of the solution was 1 mol/ml and molar ratio of ZnO to DEA was maintained at 1:1 before to the deposition.

[LOW] Similarity: 4.65%

Sentence: Glass plate was used as a substrate and it was cleaned with soap solution, Chromic acid at 50-Cthe glass substrate was cleaned using by soap solution, chromic acid, Distilled water, Acetone.

Plagiarism Detection Report

[LOW] Similarity: 3.85%

Sentence: Fresh (1 -4 mol%) dopant solution was deposited by spin coating method the sol at a rotation speed of 1000 rpm for 1 minutes and film were heated at 300-C for 10 min t and cooled down to room temperature.

[LOW] Similarity: 13.06%

Sentence: The process of coating is repeated 15 times in order to get the desired thic kness of the thin film.

[LOW] Similarity: 2.94%

Sentence: Finally the film was heated in muffle furnace at 300-C for 2 hrs and cooled down room temperature.

[LOW] Similarity: 5.88%

Sentence: The structural properties of the ZnO thin films were characterized by an X -Ray diffractometer (Cu K α radiation) [7].

[LOW] Similarity: 3.45%

Sentence: The optical transmittance measurement was carried out using UV -VIS spectrophotometer [7].

[LOW] Similarity: 0.00%

Sentence: FTIR measurements were performed in the spectral region 350 -1600 cm⁻¹[8].

[LOW] Similarity: 3.33%

Sentence: Room temperature photoluminescence measurements were carried out using a spectrofluorometer using an excit ation wavelength of 250 nm [9].

[LOW] Similarity: 7.41%

Plagiarism Detection Report

Sentence: The surface morphology of the films was observed by using scanning electron microscopy [9].

[LOW] Similarity: 0.00%

Sentence: III.

[LOW] Similarity: 7.69%

Sentence: RESULT AND ANALYSIS

A. Ftir Analysis

A predominant ester C=O stretching vibration is observed in the range 1879 -1899 cm⁻¹ as a sharp peak in all four combination.

[LOW] Similarity: 2.78%

Sentence: It is

quite understandable that there are no significant changes in the Zinc acetate molecule was found due to the moderate temperature value at the reaction condition.

[LOW] Similarity: 7.09%

Sentence: Though the molar concentration of Zinc acet ate is constant and the concentration of Aluminium chloride Anhydrite are varied and studied.

[LOW] Similarity: 8.33%

Sentence: The comparative study of IR spectrum indicates that the first trial with th e 1 mole addition of AlCl 3nH 2O in to the 1 mole of Zinc acetate didn't show any sharp or broad peaks in the range of 3000 and above whereas, due to the increasing the molar concentration of AlCl 3nH 2O there will be the appearance of some characteristic sharp peaks in the range of 3000 and above, These comparisons indicates that when incre asing the molar concentration of AlCl 3nH 2O, the evaporation of water molecules are hindered during the reaction condition.

Plagiarism Detection Report

[LOW] Similarity: 3.31%

Sentence: They will stick with Zinc atom by the co-ordinate covalent bond and showing the significant vibration of O-H stretching on the IR spectrum.

[LOW] Similarity: 6.90%

Sentence: Besides, the common Al-Cl and Zn-Cl stretching are also observed in the range of 600-1000 cm^{-1} .

[LOW] Similarity: 0.00%

Sentence: Usually, the co-ordinate covalent bonds are comparatively weaker than the co-valent bonds but the molecule formed during the reaction are kinetically and thermodynamically stable.

[LOW] Similarity: 3.57%

Sentence: [9, 10].

[LOW] Similarity: 0.00%

Sentence: .

[LOW] Similarity: 2.68%

Sentence: Fig (3.1.1) 1mole

Fig (3.1.2) 2mole

Fig (3.1.3) 3 mole

Fig (3.1.4) 4 mole

Fig No.3.1 .

[LOW] Similarity: 0.42%

Sentence: FTIR for Aluminium Chloride Anhydrite (Al) doped Zinc acetate dehydrate (ZnO) FTIR
-B-D-1M-Name Description4000 400 3500 3000 2500 2000 1500 1000 500100
0102030405060708090
 cm^{-1} % T

Plagiarism Detection Report

1899.45cm-11188.59c m-1

1121.92cm-1906.31cm-1

1143.92cm-11234.72cm-1 937.09cm-1

829.83cm-1

1025.63cm-1880.15cm-1

770.34cm-11279.33cm-1

976.05cm-1716.03cm-1 1382.71cm-1 1695.28c m-1

1325.14cm-11763.25cm-11729.78cm-1

1633.98cm-11558.82cm-11459.53cm -1

1430.63c m-11497.93cm-1 553.05cm-1

459.86cm-11820.53cm-1 415.45cm-1607.01cm -1

488.06cm-1513.32cm- 1

651.08cm-1

FTIR-B-D-2M-Name Description4000 400 3500 3000 2500 2000 1500 1000 500100

0102030405060708090

cm-1% T

187 9.42cm-11132 .20cm-111 60.4 5c m-1876.12cm-1159 1.88cm-1 969.09cm-1

824.66cm- 1143 4.14 c m-113 59.2 8c m-11245.82cm-1 60 9.36cm-1 1017.15cm-1 1475.97cm- 1

708.74cm- 11761 .14cm-1 1 290.4 4cm-1

1631.75cm- 1557.50cm- 1645.15cm-1 2884.46cm-1

754.0 5cm-13380.31cm-1 172 0.22cm-11806.75cm- 1457 .90cm-14 11.13 c m-1

FTIR-B-D-3M-Name Description4000 400 3500 3000 2500 2000 1500 1000 500100

0102030405060708090

cm-1% T

18 99.82cm-11137 .1 4cm-1119 6.54cm-1 788 .36 cm-1

1096 .6 3cm-19 78.12cm-1848 .11 cm-1 17 35.74cm-1

1 761 .19 cm-113 99.53cm-1

90 1.3 4cm-164 8.11cm-1 125 1.07cm-1

1344 .2 5cm-11 298.07 cm-1 10 38.95 cm-1 1 463 .00 cm-1

1 591.00 cm-11636 .1 8cm-1579 .23 cm-1155 3.35cm-1150 4.6 5cm -1

Plagiarism Detection Report

3 171.42 cm-1704 .44cm- 1

32 74.25cm-15 07.72cm-1465 .1 1cm-1

FTIR-B-D-4M-Name Description4000 400 3500 3000 2500 2000 1500 1000 500100

0102030405060708090

cm-1% T

1898.23cm- 11 340.42cm-1 111 5.54 c m-1

1187 .94cm-1839.82cm- 1

788 .81cm-13377.81cm- 1

883 .11cm-11252.66cm-1 970.42cm-1

1396.89cm- 1

936.93cm-12887.22cm- 1

104 2.58 c m-11593.19cm- 1 713.23cm- 1

579.66cm- 1

604.40cm-1

652.98cm-11479.50cm- 11786.16cm-1

16 98.2 5c m-1

1729.61cm- 11637.26cm-1462 .11cm-1

4 07.12 c m-1

International Journal for Research in Applied Science & Engineering Technology (IJRASET)

ISSN: 2321 -9653; IC Value: 45.98; SJ Impact

Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

996 B. Optical Analysis

1) UV-VIS NIR Spectrum Analysis: UV-Visible Absorption spectroscopy involves measuring the absorbance of light measuring by a compound as a function of wavelength in the UV -Visible range.

Plagiarism Detection Report

[LOW] Similarity: 17.69%

Sentence: When a molecule absorbs a photon of UV -VIS light, the molecule is excited from its ground state to an electronic excited state.

[LOW] Similarity: 13.88%

Sentence: In other words, an electron is promoted from the HOMO (Highest -energy Occupied Molecular Orbital) of the molecule to the LUMO (Lowest -energy Unoccupied Molecular Orbital) of the molecule.

[LOW] Similarity: 7.69%

Sentence: For most conjugated molecules, the photons with the correct amount of energy just happened to visible light.

[LOW] Similarity: 6.90%

Sentence: The wavelength which is most strongly observed by a compound is called λ_{max} .

[LOW] Similarity: 5.13%

Sentence: Here Aluminium Chloride

Anhydrite (Al) doped Zinc acetate dehydrate (ZnO) thin film shows λ_{max} as 371.50 nm which invisible region (violet or blue).

[LOW] Similarity: 15.19%

Sentence: This is shown in UV absorption spectrum .

[LOW] Similarity: 6.03%

Sentence: Optical transmission spectra of an Aluminium chloride dehydrate doped in different concentration with ZnO thin films are shown in (3.2.1) here the wavelength is taken from 300 to 800 nm, this spectra reveals all films exhibited higher transmittance than 85% within the visible region which has sharp absorption edge when an Al

Plagiarism Detection Report

concentration increase the absorption becomes broadening its indicating the increasing the optical band gap that is the blue shift

of the absorption edge of the Al doped ZnO thin films are associated with an increase of the carrier concentration blocking the

lowest state in the conduction band it is known as Burstein -Moss effect.

[LOW] Similarity: 0.00%

Sentence: 11,12].

[LOW] Similarity: 5.88%

Sentence: The refractive index and thickness of a thin film can be calculated from a simple transmittance spectrum using the Swanepoel method.

[LOW] Similarity: 4.44%

Sentence: a) The Refractive Index

$$n = [N + (N^2 - S^2)^{1/2}]^{1/2}$$

Where $N = 2S$? ? ? ? ?

$$?? ?? + ???? ?$$

?

S - Refractive index of the substrate (1.655)

TM, Tm - Maximum and Minimum transmittance envelope functions

TM(?), T m(?)

N=1.86

The refractive index of the Aluminium Chloride Anhydrite (Al) doped Zinc acetate dehydrate (ZnO) thin film is

N=1.86

b) Thickness of the Thin Film

$$d = M ? ? ? ? ?$$

$$?(? ? ? ? ? ? ? ? ? ?)$$

M=1 for two adjacent maxima or minima

Plagiarism Detection Report

$n_1 = n(\lambda_1)$ and $n_2 = n(\lambda_2)$

$d = \frac{\lambda}{4(n_1^2 - n_2^2)}$ (???)

$\frac{1}{d} = \frac{4(n_1^2 - n_2^2)}{\lambda}$

$d = 8.3955 \times 10^{-8}$

$d = 0.839 \times 10^{-9} \text{ m}$

Thickness of the thin film $d = 0.839 \times 10^{-9} \text{ m}$

Fig No.

[LOW] Similarity: 2.28%

Sentence: 3.2.1 UV for Aluminium Chloride Anhydrite (Al) doped Zinc acetate dehydrate (ZnO)

International Journal for Research in Applied Science & Engineering Technology (IJRASET)

ISSN: 2321 -9653; IC Value: 45.98; SJ Impact

Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

997 2) Photoluminance Analysis: Photoluminescence analysis is a very conventional and an effective tool for characterizing and evaluating luminescence material.

[LOW] Similarity: 4.35%

Sentence: The Photoluminescence spectra of AZO thin film for different doping concentration was recorded at room temperature which is shown in fig () from these we observed two distinct peaks for all doping concentration in near band edge emission and deep level emission the near band edge peaks are due to free exciton recombination and the deep

Plagiarism Detection Report

level emission are related to oxygen defects [13, 15] when increasing the Al concentration the orange colour emission peaks

are disappeared because of Al ions exist in Al^{3+} and Zn ions in Zn^{2+} , when Al is doped with ZnO Al ions can consume residual

O ions and decrease the concentration of interspatial oxygen in the AZO thin films.

[LOW] Similarity: 3.04%

Sentence: Fig No.3.2.2 PL for Aluminium Chloride Anhydrite (Al) doped Zinc acetate dehydrate (ZnO) IV.

[LOW] Similarity: 14.42%

Sentence: MORPHOLOGICAL STUDIES A.

[LOW] Similarity: 7.89%

Sentence: Structural Studies

The crystal structure of the as deposited ZnO: Al films with Different molar concentration (1,2,3,4 mol%) were studied using X-ray diffraction technique.

[LOW] Similarity: 4.48%

Sentence: The XRD patterns obtained for the films deposited from the starting solutions having different solvent volumes are shown in the fig (4.1).

[LOW] Similarity: 3.03%

Sentence: The diffraction peaks appeared in the spectrum have been identified and indexed using the standard diffraction data (JCPDS card no: 36 -1451).

[LOW] Similarity: 6.67%

Sentence: The interplanar spacing (d) confirms that the deposited films are of ZnO with

Plagiarism Detection Report

hexagonal structure.

[LOW] Similarity: 2.78%

Sentence: The X -ray diffraction profiles clearly showed that all the films have preferential orientation along the (002) plane with hexagonal wurtzite structure irrespective of the solvent volume.

[LOW] Similarity: 3.03%

Sentence: Even though there is no significant impact of solvent volume on the preferential orientation plane, the degree of preferential orientation growth varies with the change in the solvent volume.

[LOW] Similarity: 2.78%

Sentence: The preferential orientation is caused by the minimization of the internal stress and surface energy and it is well known that in a ZnO crystal the (002) orientation has the lowest surface energy density.

[LOW] Similarity: 0.00%

Sentence: [16,17].

[LOW] Similarity: 1.39%

Sentence: International Journal for Research in Applied Science & Engineering Technology (IJRASET)
ISSN: 2321 -9653; IC Value: 45.98; SJ Impact
Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

998

Plagiarism Detection Report

Fig 4.1 (a) XRD pattern of ZnO:Al films prepared from different molar dopant concentration(mol) 1 mol %

Pos.

[LOW] Similarity: 10.42%

Sentence: [°2 θ] Height

[cts] FWHM

Left [°2θ] d-spacing

[Å] Rel.

[LOW] Similarity: 0.00%

Sentence: Int.

[LOW] Similarity: 2.99%

Sentence: [%]

6.3119 129.58 0.7590 13.99173 7.32

9.4484 94.49 0.2007 9.35290 5.34

10.8090 61.71 1.0867 8.17842 3.48

11.9080 73.20 0.3740 7.42600 4.13

13.8345 109.54 2.9344 6.39593 6.19

22.6954 619.54 3.1154 3.91486 34.98

24.7751 511.90 2.4487 3.59075 28.91

Fig 4.1.2 (b) XRD pattern of ZnO:Al films prepared from different molar dopant concentration(mol) 2 mol %

Plagiarism Detection Report

Pos.

[LOW] Similarity: 10.42%

Sentence: [°2 ?]

Height

[cts] FWHM

Left [°2?] d-spacing

[Å] Rel.

[LOW] Similarity: 0.00%

Sentence: Int.

[LOW] Similarity: 5.42%

Sentence: [%]

6.5724 210.93 1.0915 13.43780 46.39

9.8877 167.85 1.7643 8.93830 36.92

12.4947 201.27 2.0207 7.07857 44.27

14.4510 196.44 0.2515 6.12444 43.20

22.1137 454.67 7.1144 4.01651 100.00

24.6846 420.75 3.8725 3.60370 92.54

International Journal for Research in Applied Science & Engineering Technology (IJRASET)

ISSN: 2321 -9653; IC Value: 45.98; SJ Impact

Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

999 Pos.

Plagiarism Detection Report

[LOW] Similarity: 10.42%

Sentence: [°2 θ] Height

[cts] FWHM

Left [°2θ] d-spacing

[Å] Rel.

[LOW] Similarity: 0.00%

Sentence: Int.

[LOW] Similarity: 2.97%

Sentence: [%]

7.4774 187.66 1.5923 11.81328 14.26

13.3067 145.96 1.4690 6.64839 11.09

20.6660 250.18 3.5252 4.29449 19.01

24.1408 594.93 3.5572 3.68364 45.21

28.9863 95.39 0.8024 3.07795 7.25

31.6885 1316.01 0.0520 2.82137 100.00

35.6939 68.94 0.1082 2.51341 5.24

38.3519 228.47 0.9845 2.34511 17.36

42.4906 130.99 1.2301 2.12578 9.95

53.9631 70.10 1.2814 1.69780 5.33

55.8862 45.46 0.8942 1.64385 3.45

Fig 4.1.3 (c) XRD pattern of ZnO:Al films prepared from different molar dopant concentration(mol) 3 mol %

Plagiarism Detection Report

Fig 4.1.4 (d) XRD pattern of ZnO:Al films prepared from different molar dopant concentration(mol) 4 mol %

1) Structural Parameters

The following are the formula used for calculating structural parameters.

[LOW] Similarity: 7.41%

Sentence: $D = 0.94 \lambda / \cos \theta$ (Scherrer formula)

D = The size of the crystallites.

[LOW] Similarity: 4.76%

Sentence: λ The X -ray wavelength.

[LOW] Similarity: 9.09%

Sentence: 2θ The maximum of Bragg diffraction peak (in radians).

[LOW] Similarity: 0.50%

Sentence: $\Delta 2\theta$ Peak's full width at half maximum (FWHM).

[LOW] Similarity: 7.90%

Sentence: $D = \frac{0.94 \lambda}{\cos \theta} \times \frac{1}{\Delta 2\theta}$

$\frac{0.94 \lambda}{\cos \theta} \times \frac{1}{\Delta 2\theta}$

$D = \frac{0.94 \lambda}{\cos \theta} \times \frac{1}{\Delta 2\theta}$

$\frac{0.94 \lambda}{\cos \theta} \times \frac{1}{\Delta 2\theta}$

$D = 14.94 \text{ \AA}$

Pos.

[LOW] Similarity: 10.42%

Plagiarism Detection Report

Sentence: [°2 ?] Height

[cts] FWHM

Left [°2?] d-spacing

[Å] Rel.

[LOW] Similarity: 0.00%

Sentence: Int.

[LOW] Similarity: 0.81%

Sentence: [%]

5.8315 209.80 0.9967 15.14316 5.04

8.4143 74.04 0.8311 10.49985 1.78

22.5926 462.94 4.7577 3.93245 11.13

27.7198 354.33 5.3315 3.21563 8.52

31.6848 4159.46 0.0537 2.82169 100.00

48.6962 105.55 0.9943 1.86839 2.54

66.2140 223.65 0.1744 1.41028 5.38

77.2491 83.32 0.0842 1.23403 2.00

International Journal for Research in Applied Science & Engineering Technology (IJRASET)

ISSN: 2321 -9653; IC Value: 45.98; SJ Impact

Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

1000

Plagiarism Detection Report

B. Morphological Properties

Fig (4.2) show s SEM micrograph s that were taken at res olution of (a) 5?m(b) 10 ?m(c) 100 ?m(d) 100 ?m for 1,2,3 and 4 molar dopant concentration, respectively.

[LOW] Similarity: 9.17%

Sentence: Fig (a) shows uniform plan fill with some grains from fig b, c and d shows when the doping concentration increase the density of the incorporate crystals were increase d on the surface of the film and these grains are more or less cover the substrate uniformly.

[LOW] Similarity: 12.04%

Sentence: Th e SEM micrograph portraits that the agglomerated practical size decreas e with in creasing the Al concentration after the an nealing tre atment.

[LOW] Similarity: 2.85%

Sentence: The Al doped ZnO film having some fractures on the surfaces, this fracture properly results from the different in thermal expansion coefficient between film and substrate during cooling.

[LOW] Similarity: 0.00%

Sentence: [18].

[LOW] Similarity: 4.99%

Sentence: Fig (a) 1 mole Fig (b) 2 mole

Fig (c) 3 mole Fig (d) 4 mole

Fig.

[LOW] Similarity: 5.32%

Plagiarism Detection Report

Sentence: 4.2 Shows Morphological image (SEM)

V. CONCLUSION

For the purpose of photonic applications AZO thin films was coated in glass substrate with different doping concentration by sol-gel spin coating method.

[LOW] Similarity: 3.93%

Sentence: An optical and Morphological studies were carried out for coated thin films.

[LOW] Similarity: 2.22%

Sentence: From FTIR analysis we confirmed the functional group of coated thin film and we observed Al atoms are sticks with Zinc by the covalent band and produced significant O-H stretching on the IR spectrum.

[LOW] Similarity: 4.13%

Sentence: The optical characteristic of the coated thin film were confirmed with UV-VIS NIR spectrum analysis, when the doping concentration the optical band gap of the AZO thin films become broader and the transmittance reaches 85% in these characteristics are very important for an optoelectronic device like LED.

[LOW] Similarity: 5.26%

Sentence: From the morphological studies we confirmed the structure AZO film and estimated the grain size of the coated films for different doping concentration.

[LOW] Similarity: 6.13%

Sentence: From SEM micrographs the agglomerated practical size were decreases with increasing the Al concentration after the annealing treatment.

Plagiarism Detection Report

[LOW] Similarity: 14.54%

Sentence: REFERENCES

[1] D.B.

[LOW] Similarity: 0.62%

Sentence: Laks., C.G.

[LOW] Similarity: 0.00%

Sentence: Vandewalle., G.F.

[LOW] Similarity: 6.90%

Sentence: Neumark., S.T.

[LOW] Similarity: 8.05%

Sentence: Pantelides., Apply.Phy.Lett.63 (1993) 1375 -1377.

[LOW] Similarity: 0.00%

Sentence: [2] J.

[LOW] Similarity: 0.18%

Sentence: Pearation., D.P.

[LOW] Similarity: 20.33%

Sentence: `Norton., K. Ip, Y.W.

[LOW] Similarity: 0.00%

Sentence: Heo., T.

[LOW] Similarity: 5.98%

Sentence: Steiner., Superlattices Microstruct.

Plagiarism Detection Report

[LOW] Similarity: 0.00%

Sentence: 34 (2003) 3 -32.

[LOW] Similarity: 0.00%

Sentence: [3] H.

[LOW] Similarity: 7.55%

Sentence: Ohno., Science 281 (1998) 1502 -1503, 951; T.

[LOW] Similarity: 2.36%

Sentence: Siyama., And A.

[LOW] Similarity: 0.00%

Sentence: Kato., Anal.

[LOW] Similarity: 10.65%

Sentence: Chem., 34 (1962).

[LOW] Similarity: 0.00%

Sentence: [4] N.

[LOW] Similarity: 1.46%

Sentence: Srinatha., Y.S.

[LOW] Similarity: 4.83%

Sentence: No., B. Vinayak Kamble., Sujoy Chakravarty., N.

[LOW] Similarity: 2.24%

Sentence: Suriyamurthy., Basavarajangadi., A.M.

[LOW] Similarity: 1.57%

Plagiarism Detection Report

Sentence: Umarji., W.K.

[LOW] Similarity: 4.55%

Sentence: Choi., RSC., Adv.

[LOW] Similarity: 0.00%

Sentence: 6 (2016) 9779.

[LOW] Similarity: 0.00%

Sentence: [5] B.K.

[LOW] Similarity: 9.34%

Sentence: Shrma., N.

[LOW] Similarity: 0.00%

Sentence: Khare., J.Phy.

[LOW] Similarity: 0.00%

Sentence: D.Appl.

[LOW] Similarity: 2.23%

Sentence: Phys.43 (2010) 465402.

[LOW] Similarity: 0.00%

Sentence: [6] X.L.

[LOW] Similarity: 0.00%

Sentence: Wu., G.G.

[LOW] Similarity: 1.29%

Sentence: Siu., C.L.

Plagiarism Detection Report

[LOW] Similarity: 0.00%

Sentence: Fu., H.C.

[LOW] Similarity: 8.03%

Sentence: Ong., Appl.

[LOW] Similarity: 0.00%

Sentence: Phy.

[LOW] Similarity: 0.00%

Sentence: Lett.78 (2001) 2285.

[LOW] Similarity: 5.96%

Sentence: [7] Srinatha.

[LOW] Similarity: 11.89%

Sentence: N., Raghu.

[LOW] Similarity: 7.79%

Sentence: P., Mahesh.

[LOW] Similarity: 2.96%

Sentence: M.H., Angadi.

[LOW] Similarity: 4.00%

Sentence: B., Journal of Alloys and Compounds, 722 2017 PP (888 -895).

[LOW] Similarity: 0.00%

Sentence: Different molar

concentration (mole) D

Nm ?

Plagiarism Detection Report

x1014

Lines/m2

1 20.56 ? 0.706

2 46.96 ? 0.135

3 25.7 ? 3.6352

4 14.94 ? 3.35

International Journal for Research in Applied Science & Engineering Technology (IJRASET)

ISSN: 2321 -9653; IC Value: 45.98; SJ Impact

Factor: 7.429

Volume 9 Issue IV Apr 2021 -

Available at www.ijraset.com

©IJRASET: All Rights are Reserved

1001 [8] Thomson.

[LOW] Similarity: 3.70%

Sentence: T., Magnetic Properties of Metallic Thin fi Im 10 (2014) University of Manchester, UK.

[LOW] Similarity: 4.11%

Sentence: [9] Stefan collier And Bradley., M.

[LOW] Similarity: 9.37%

Sentence: Peterson., The.

[LOW] Similarity: 0.00%

Sentence: Astro.

[LOW] Similarity: 4.88%

Sentence: Journal, 555: 775 -785 (2001).

Plagiarism Detection Report

[LOW] Similarity: 0.00%

Sentence: [10] A.

[LOW] Similarity: 12.52%

Sentence: Carlos., Rosas -casarez., P.

[LOW] Similarity: 4.69%

Sentence: Susana., M. Arredondo -rea., Gomez -soberon., L.

[LOW] Similarity: 0.00%

Sentence: Jorge., Alamaral -sanchez., Ramon corral -Higuera., M.J. Chinchillas -Chinchillas and Octavio H. Acuna -Aguero., IJCSIA.

[LOW] Similarity: 14.85%

Sentence: Volume 4: issue 4 (2014).

[LOW] Similarity: 0.00%

Sentence: [11] M.

[LOW] Similarity: 3.07%

Sentence: Maache., T.

[LOW] Similarity: 0.00%

Sentence: Devers., A.

[LOW] Similarity: 8.66%

Sentence: Chala., Semiconductors, 51 (2017) pp.

[LOW] Similarity: 2.61%

Sentence: 1604 -1610.

Plagiarism Detection Report

[LOW] Similarity: 5.07%

Sentence: [12] Zhaonancia., Yi liu., Kelly chance., R. Caroline nowlan., Ruediger lang., Journal.

[LOW] Similarity: 0.00%

Sentence: Geo.

[LOW] Similarity: 16.28%

Sentence: Research., Vol.

[LOW] Similarity: 4.15%

Sentence: 117., (2012).

[LOW] Similarity: 0.28%

Sentence: [13] D. M. Bagnall, Y. F. Chen, Z. Zhu, T. Yao, M. Y. Shen, and T. Goto, Appl.

[LOW] Similarity: 0.00%

Sentence: Phys.

[LOW] Similarity: 0.00%

Sentence: Lett .

[LOW] Similarity: 0.00%

Sentence: 73, 1038 (1998) .

[LOW] Similarity: 3.68%

Sentence: [14] B. Lin and Z. Fu, Appl.

[LOW] Similarity: 0.00%

Sentence: Phys.

[LOW] Similarity: 0.00%

Plagiarism Detection Report

Sentence: Lett.

[LOW] Similarity: 4.75%

Sentence: 79, 943 (2001).

[LOW] Similarity: 5.35%

Sentence: [15] ZanyarMovasaghi., Shazza Rehman., Ihteshamur Rehman., App.

[LOW] Similarity: 0.00%

Sentence: Spec.

[LOW] Similarity: 12.17%

Sentence: R ev, 43: 134 -179 (2008).

[LOW] Similarity: 0.00%

Sentence: [16] Z.R.

[LOW] Similarity: 3.27%

Sentence: Khan., M.S.

[LOW] Similarity: 0.00%

Sentence: Khan., M.

[LOW] Similarity: 0.33%

Sentence: Zulfequar., M.S.

[LOW] Similarity: 3.43%

Sentence: Khan., Mater.

[LOW] Similarity: 0.00%

Sentence: Sci.

Plagiarism Detection Report

[LOW] Similarity: 0.00%

Sentence: Appl.

[LOW] Similarity: 0.00%

Sentence: 2 (2011) 340 -345.

[LOW] Similarity: 0.00%

Sentence: [17] L.

[LOW] Similarity: 0.00%

Sentence: Li., L.

[LOW] Similarity: 0.00%

Sentence: Fang., X.M.

[LOW] Similarity: 0.00%

Sentence: Chen., J.

[LOW] Similarity: 2.22%

Sentence: Liu., F.F.

[LOW] Similarity: 1.50%

Sentence: Yang., Q.J.

[LOW] Similarity: 0.00%

Sentence: Li., G.B.

[LOW] Similarity: 0.43%

Sentence: Liu., S.J.

[LOW] Similarity: 4.68%

Plagiarism Detection Report

Sentence: Feng., Phys.

[LOW] Similarity: 6.43%

Sentence: E 41 (2008) 169 -174.

[LOW] Similarity: 0.00%

Sentence: [18] H.

[LOW] Similarity: 0.00%

Sentence: Zhou., D.

[LOW] Similarity: 0.00%

Sentence: Yi., Z.

[LOW] Similarity: 5.15%

Sentence: Yu., L. Xiao ., J.

[LOW] Similarity: 0.00%

Sentence: Li., Thin solid Films 515 (2007) 1326 -1337.

[LOW] Similarity: 0.00%

Sentence: [19] T.H.

[LOW] Similarity: 3.85%

Sentence: Gfroerer., (2006) Photoluminescence in Analysis of Surface and InterfacesEncyclopediaof Analytical Chemistry.

[LOW] Similarity: 0.00%

Sentence: [20] S.

[LOW] Similarity: 8.09%

Sentence: Leela., A. Sakshi Joshi., S.

Plagiarism Detection Report

[LOW] Similarity: 8.69%

Sentence: Monika., AIP Conf.

[LOW] Similarity: 7.00%

Sentence: proc.2117,020019 -1-020019 -3.

[LOW] Similarity: 6.85%

Sentence: [21] F. Yakupha noglu., Y.

[LOW] Similarity: 8.88%

Sentence: CaGlar., S.

[LOW] Similarity: 7.33%

Sentence: Ilican., M.

[LOW] Similarity: 4.18%

Sentence: Caglar., Physica B 394, 86 (2007).

[LOW] Similarity: 0.00%

Sentence: [22] T.

[LOW] Similarity: 4.21%

Sentence: Lancnova., A.

[LOW] Similarity: 7.77%

Sentence: Harizonova., T.

[LOW] Similarity: 1.62%

Sentence: Koutzarov., B.

[LOW] Similarity: 4.90%

Plagiarism Detection Report

Sentence: Vertruven., Materials Latter 64 (2010) 1147 -1149.

[LOW] Similarity: 0.00%

Sentence: [23] A.

[LOW] Similarity: 3.00%

Sentence: Mahroug., S.

[LOW] Similarity: 2.32%

Sentence: Boudjadr., S.

[LOW] Similarity: 4.56%

Sentence: Hamrit., L.

[LOW] Similarity: 4.15%

Sentence: Guerbous., Materials Latter 134 (2014) 248 -251.

[LOW] Similarity: 0.00%

Sentence: [24] M.

[LOW] Similarity: 0.00%

Sentence: Yan., M.

[LOW] Similarity: 1.36%

Sentence: Lane., R.C.

[LOW] Similarity: 3.75%

Sentence: Kannewurf., H.P.

[LOW] Similarity: 7.85%

Sentence: Changr., Appl.

Plagiarism Detection Report

[LOW] Similarity: 0.00%

Sentence: Phys.

[LOW] Similarity: 0.00%

Sentence: Lett.

[LOW] Similarity: 0.90%

Sentence: 78(2001)2342.

[LOW] Similarity: 5.03%

Sentence: [25] M.A.A.

[LOW] Similarity: 4.05%

Sentence: Farag., M.

[LOW] Similarity: 3.33%

Sentence: Cavan., F.

[LOW] Similarity: 2.39%

Sentence: Yakuphanoglu., Mater.

[LOW] Similarity: 0.00%

Sentence: Chem.

[LOW] Similarity: 0.00%

Sentence: Phys.

[LOW] Similarity: 2.76%

Sentence: 132(2012)550.

[LOW] Similarity: 0.00%

Plagiarism Detection Report

Sentence: [26] R.

[LOW] Similarity: 0.00%

Sentence: Maity., K.K.

[LOW] Similarity: 9.56%

Sentence: Chattopadhy., Sol.Energy.Mater.Sol.Cells.90(2006)597.

[LOW] Similarity: 10.12%

Sentence: [27] A. Gu lino., F.

[LOW] Similarity: 8.42%

Sentence: Castelli., P.

[LOW] Similarity: 5.40%

Sentence: Dapporto., P.

[LOW] Similarity: 2.11%

Sentence: Rossi., I.

[LOW] Similarity: 11.17%

Sentence: Fragala., Chem.

[LOW] Similarity: 4.44%

Sentence: Mater.14 (2002)704.

[LOW] Similarity: 0.00%

Sentence: [28] A.V.

[LOW] Similarity: 0.63%

Sentence: Moholkar, L.G.

Plagiarism Detection Report

[LOW] Similarity: 1.83%

Sentence: Agawane., U.

[LOW] Similarity: 0.00%

Sentence: Simk., Y.

[LOW] Similarity: 0.00%

Sentence: Kwon., S.

[LOW] Similarity: 5.09%

Sentence: Choid., Y.

[LOW] Similarity: 11.04%

Sentence: Rajpurek., H.

[LOW] Similarity: 5.07%

Sentence: Kimj., Alloy.Comp.

[LOW] Similarity: 3.23%

Sentence: 50 6 (2010)794.

[LOW] Similarity: 0.00%

Sentence: [29] K.

[LOW] Similarity: 1.95%

Sentence: Usharani., A.R.

[LOW] Similarity: 3.93%

Sentence: Balu., V.S.

[LOW] Similarity: 12.60%

Plagiarism Detection Report

Sentence: Nagarethinam., Surf.Engg.

[LOW] Similarity: 2.57%

Sentence: 3 2(2016)829.

[LOW] Similarity: 0.00%

Sentence: [30] N.

[LOW] Similarity: 4.84%

Sentence: Lejimin., O.

[LOW] Similarity: 11.82%

Sentence: Savadoga., SolarEnergyMater Sol Cells, 70 (2001)71.

[LOW] Similarity: 5.59%

Sentence: [31] M. Caglar.

[LOW] Similarity: 0.00%

Sentence: Y.

[LOW] Similarity: 8.88%

Sentence: Caglar., S.

[LOW] Similarity: 5.63%

Sentence: Ilcan., J.OptoelectronicAdv.

[LOW] Similarity: 0.00%

Sentence: Mater.

[LOW] Similarity: 1.21%

Sentence: 8, 1410 (2006).

Plagiarism Detection Report

[LOW] Similarity: 0.00%

Sentence: [32] J.H.

[LOW] Similarity: 3.58%

Sentence: Lee., B.O.

[LOW] Similarity: 5.95%

Sentence: Park., Thin Solid Films, 426 (2003) pp.

[LOW] Similarity: 0.00%

Sentence: 94 -99.

[LOW] Similarity: 0.00%

Sentence: [33] T.

[LOW] Similarity: 0.77%

Sentence: Jannane., M.

[LOW] Similarity: 0.14%

Sentence: Manoua., A.

[LOW] Similarity: 9.20%

Sentence: Liba., N.

[LOW] Similarity: 8.08%

Sentence: Fazouan., A. El Hichou., A.

[LOW] Similarity: 5.35%

Sentence: Almaggoussi., A.

[LOW] Similarity: 6.73%

Plagiarism Detection Report

Sentence: Outzourhit., M.

[LOW] Similarity: 4.32%

Sentence: Chail., J.

[LOW] Similarity: 0.00%

Sentence: Mater.

[LOW] Similarity: 0.00%

Sentence: Environ.

[LOW] Similarity: 0.00%

Sentence: Sci.

[LOW] Similarity: 3.76%

Sentence: 8 (2 017) pp.

[LOW] Similarity: 0.00%

Sentence: 160 -168.

[LOW] Similarity: 0.00%

Sentence: [34] Pin wang., Engfei&lang., Chengzhouzhu., Yuemingzhai., Dejun., Wang., Shajoundeng., Nano Res, 3(11) : 794-799 (2010).

[LOW] Similarity: 8.05%

Sentence: [35] Aluu., Ghazai.

[LOW] Similarity: 4.30%

Sentence: J., E mad., Salman.

[LOW] Similarity: 0.13%

Sentence: A., Zahraa., Jabbar.

Plagiarism Detection Report

[LOW] Similarity: 8.03%

Sentence: A., American Scientific Research Journal for Engineering, Technology, and Sciences, 26 (2016)

PP 202 -

211.